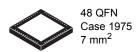
Data Sheet: Technical Data

Document Number: MC9RS08LA8

Rev. 2, 1/2012



MC9RS08LA8





MC9RS08LA8

Features:

- 8-Bit RS08 Central Processor Unit (CPU)
 - Up to 20 MHz CPU at 2.7 V to 5.5 V across temperature range of –40°C to 85°C
 - Subset of HC08 instruction set with added BGND instruction
- · On-Chip Memory
 - 8 KB flash read/program/erase over full operating voltage and temperature
 - 256-byte random-access memory (RAM)
 - Security circuitry to prevent unauthorized access to flash contents
- Power-Saving Modes
 - Wait and stop
- Clock Source Options
 - Oscillator (XOSC) Loop-control Pierce oscillator; crystal or ceramic resonator range of 31.25 kHz to 39.0625 kHz or 1 MHz to 16 MHz
 - Internal clock source (ICS) Internal clock source module containing a frequency-locked-loop (FLL) controlled by internal or external reference; supports bus frequencies up to 10 MHz
- · System Protection
 - Watchdog computer operating properly (COP) reset with option to run from dedicated 1 kHz internal clock source or bus clock
 - Low-voltage detection with reset or interrupt; selectable trip points
 - Illegal opcode detection with reset
 - Illegal address detection with reset
 - Flash block protection
- Development Support
 - Single-wire background debug interface
 - Breakpoint capability to allow single breakpoint setting during in-circuit debugging
- Peripherals

- LCD Up to 8 × 21 or 4 × 25 segments; compatible with 5 V or 3 V LCD glass displays using on-chip charge pump; functional in wait, stop modes for very low power LCD operation; frontplane and backplane pins multiplexed with GPIO functions; selectable frontplane and backplane configurations
- ADC 6-channel, 10-bit resolution; 2.5 μs conversion time; automatic compare function; 1.7 mV/°C temperature sensor; internal bandgap reference channel; operation in stop; fully functional from 2.7 V to 5.5 V.
- TPM One 2-channel 16-bit timer/pulse-width modulator (TPM) module
- SCI One 2-channel serial communications interface module with optional 13-bit break; LIN extensions
- SPI One serial peripheral interface module in 8-bit data length mode with a receive data buffer hardware match function
- ACMP Analog comparator with option to compare to internal reference
- MTIM One 8-bit modulo timer
- **KBI** 8-pin keyboard interrupt module
- RTI One real-time interrupt module with optional reference clock.
- Input/Output
 - 33 GPIOs including 1 output only pin and 1 input only pin.
 - Hysteresis and configurable pullup device on all input pins; configurable slew rate and drive strength on all output pins.
- · Package Options
 - 48-pin QFN
 - 48-pin LQFP

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Revision History

To provide the most up-to-date information, the revision of our documents on the World Wide Web will be the most current. Your printed copy may be an earlier revision. To verify you have the latest information available, refer to:

http://freescale.com/

The following revision history table summarizes changes contained in this document.

Revision	Date	Description of Changes
1	10/9/2008	Initial public released.
2	1/30/2012	Updated the case number of 48-pin QFN to 1975; updated 48-pin QFN case outline drawing.

Related Documentation

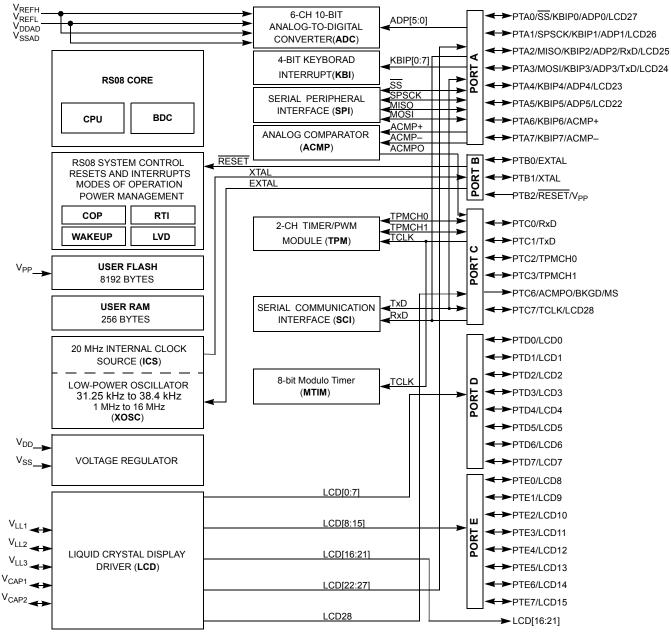
Find the most current versions of all documents at: http://www.freescale.com

Reference Manual (MC9RS08LA8RM)

Contains extensive product information including modes of operation, memory, resets and interrupts, register definition, port pins, CPU, and all module information.

1 MCU Block Diagram

The block diagram, Figure 1, shows the structure of the MC9RS08LA8 MCU.



- NOTES:
 - 1. PTB2/RESET/V_{PP} is an input only pin when used as port pin
 - 2. PTC6/ACMPO/BKGD/MS is an output only pin

Figure 1. MC9RS08LA8 Series Block Diagram

MC9RS08LA8 Series MCU Data Sheet, Rev. 2

2 Pin Assignments

This section shows the pin assignments in the packages available for the MC9RS08LA8 series.

Table 1. Pin Availability by Package Pin-Count

Pin Number			< Lowest F	Priority> High	nest	
48	Port Pin	Alt 1	Alt 2	Alt 3	Alt 4	Alt 5
1	PTD7					LCD7
2	PTD6					LCD6
3	PTD5					LCD5
4	PTD4					LCD4
5	PTD3					LCD3
6	PTD2					LCD2
7	PTD1					LCD1
8	PTD0					LCD0
9						V _{CAP1}
10						V _{CAP2}
11						V _{LL1}
12						V _{LL2}
13						V _{LL3}
14	PTA6	KBIP6	ACMP+			
15	PTA7	KBIP7	ACMP-			
16				V _{SSAD} /V _{REFL}		
17				V _{DDAD} /V _{REFH}		
18	PTB0			EXTAL		
19	PTB1			XTAL		
20				V_{DD}		
21				V _{SS}		
22	PTB2		RESET	V _{PP}		
23	PTC0		RxD			
24	PTC1		TxD			
25	PTC2		TPMCH0			
26	PTC3		TPMCH1			
27	PTC6	ACMPO	BKGD	MS		
28	PTC7		TCLK			LCD28
29	PTA0	SS	KBIP0	ADP0		LCD27
30	PTA1	SPSCK	KBIP1	ADP1		LCD26
31	PTA2	MISO	KBIP2	RxD	ADP2	LCD25

Table 1. Pin Availability by Package Pin-Count (continued)

Pin Number < Lowest Priority					ority> Highest			
48	Port Pin	Alt 1	Alt 2	Alt 3	Alt 4	Alt 5		
32	PTA3	MOSI	KBIP3	TxD	ADP3	LCD24		
33	PTA4		KBIP4	ADP4		LCD23		
34	PTA5		KBIP5	ADP5		LCD22		
35						LCD21		
36						LCD20		
37						LCD19		
38						LCD18		
39						LCD17		
40						LCD16		
41	PTE7					LCD15		
42	PTE6					LCD14		
43	PTE5					LCD13		
44	PTE4					LCD12		
45	PTE3					LCD11		
46	PTE2					LCD10		
47	PTE1					LCD9		
48	PTE0					LCD8		

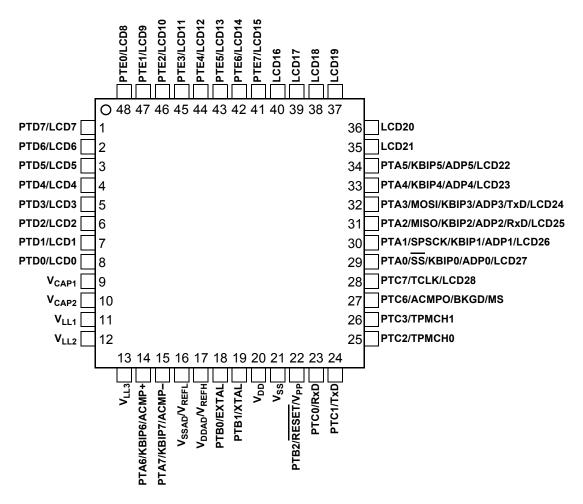


Figure 2. MC9RS08LA8 Series in 48-Pin QFN/LQFP Package

This chapter contains electrical and timing specifications.

3.1 Parameter Classification

The electrical parameters shown in this supplement are guaranteed by various methods. To give the customer a better understanding the following classification is used and the parameters are tagged accordingly in the tables where appropriate:

Table 2. Parameter Classifications

Р	Those parameters are guaranteed during production testing on each individual device.
С	Those parameters are achieved by the design characterization by measuring a statistically relevant sample size across process variations.
Т	Those parameters are achieved by design characterization on a small sample size from typical devices under typical conditions unless otherwise noted. All values shown in the typical column are within this category.
D	Those parameters are derived mainly from simulations.

NOTE

The classification is shown in the column labeled "C" in the parameter tables where appropriate.

3.2 Absolute Maximum Ratings

Absolute maximum ratings are stress ratings only, and functional operation at the maxima is not guaranteed. Stress beyond the limits specified in Table 3 may affect device reliability or cause permanent damage to the device. For functional operating conditions, refer to the remaining tables in this chapter.

This device contains circuitry protecting against damage due to high static voltage or electrical fields; however, it is advised that normal precautions be taken to avoid application of any voltages higher than maximum-rated voltages to this high-impedance circuit. Reliability of operation is enhanced if unused inputs are tied to an appropriate logic voltage level (for instance, either V_{SS} or V_{DD}) or the programmable pull-up resistor associated with the pin is enabled.

Table 3. Absolute Maximum Ratings

Rating	Symbol	Value	Unit
Supply voltage	V_{DD}	2.7 to 5.5	V
Maximum current into V _{DD}	I _{DD}	120	mA
Digital input voltage	V _{In}	–0.3 to V _{DD} + 0.3	V
Instantaneous maximum current Single pin limit (applies to all port pins) ^{1, 2, 3}	I _D	±25	mA
Storage temperature range	T _{stg}	-55 to 150	°C

- Input must be current limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values for positive (V_{DD}) and negative (V_{SS}) clamp voltages, then use the larger of the two resistance values.
- ² All functional non-supply pins are internally clamped to V_{SS} and V_{DD} except the RESET/V_{PP} pin which is internally clamped to V_{SS} only.
- Power supply must maintain regulation within operating V_{DD} range during instantaneous and operating maximum current conditions. If positive injection current ($V_{In} > V_{DD}$) is greater than IDD, the injection current may flow out of VDD and could result in external power supply going out of regulation. Ensure external VDD load will shunt current greater than maximum injection current. This will be the greatest risk when the MCU is not consuming power. Examples are: if no system clock is present, or if the clock rate is very low which would reduce overall power consumption.

3.3 Thermal Characteristics

This section provides information about operating temperature range, power dissipation, and package thermal resistance. Power dissipation on I/O pins is usually small compared to the power dissipation in on-chip logic and voltage regulator circuits and it is user-determined rather than being controlled by the MCU design. In order to take $P_{I/O}$ into account in power calculations, determine the difference between actual pin voltage and V_{SS} or V_{DD} and multiply by the pin current for each I/O pin. Except in cases of unusually high pin current (heavy loads), the difference between pin voltage and V_{SS} or V_{DD} will be very small.

Symbol Value Unit Rating T_L to T_H Operating temperature range (packaged) T_A °C -40 to 85 °C Maximum junction temperature 105 T_{JMAX} Thermal resistance Single layer board 48-pin LQFP 71 48-pin QFN 84 °C/W Four layer board 48-pin LQFP 49 48-pin QFN

Table 4. Thermal Characteristics

The average chip-junction temperature (TJ) in °C can be obtained from:

$$T_{,l} = T_{\Delta} + (P_{D} \times \theta_{,l\Delta})$$
 Eqn. 1

where:

 $T_A = Ambient temperature, °C$

 θ_{JA} = Package thermal resistance, junction-to-ambient, °C /W

 $P_{D} = P_{int} + P_{I/O}$

 $P_{int} = I_{DD} \times V_{DD}$, Watts chip internal power

 $P_{I/O}$ = Power dissipation on input and output pins user determined

For most applications, $P_{I/O} \ll P_{int}$ and can be neglected. An approximate relationship between PD and TJ

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(if PI/O is neglected) is:

$$P_D = K \div (T_J + 273^{\circ}C)$$
 Eqn. 2

Solving Equation 1 and Equation 2 for K gives:

$$K = P_D \times (T_A + 273^{\circ}C) + \theta_{JA} \times (PD)^2$$
 Eqn. 3

where K is a constant pertaining to the particular part. K can be determined from Equation A-3 by measuring P_D (at equilibrium) for a known T_A . Using this value of K, the values of P_D and P_D and P_D are obtained by solving equations 1 and 2 iteratively for any value of P_D .

3.4 ESD Protection and Latch-Up Immunity

Although damage from electrostatic discharge (ESD) is much less common on these devices than on early CMOS circuits, normal handling precautions must be used to avoid exposure to static discharge. Qualification tests are performed to ensure that these devices can withstand exposure to reasonable levels of static without suffering any permanent damage.

All ESD testing is in conformity with AEC-Q100 Stress Test Qualification for Automotive Grade Integrated Circuits. During the device qualification ESD stresses were performed for the human body model (HBM), the machine model (MM) and the charge device model (CDM).

A device is defined as a failure if after exposure to ESD pulses the device no longer meets the device specification. Complete DC parametric and functional testing is performed per the applicable device specification at room temperature followed by hot temperature, unless specified otherwise in the device specification.

Model	Description	Symbol	Value	Unit
	Series resistance	R1	1500	Ω
Human Body	Storage capacitance	С	100	pF
	Number of pulses per pin	_	3	_
	Series resistance	R1	0	Ω
Machine	Storage capacitance	С	200	pF
	Number of pulses per pin	_	3	_
Latch up	Minimum input voltage limit	_	-2.5	V
Latch-up	Maximum input voltage limit	_	7.5	V

Table 5. ESD and Latch-up Test Conditions

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No.	Rating ¹	Symbol	Min	Max	Unit
1	Human body model (HBM)	V_{HBM}	±2000	_	V
2	Machine model (MM)	V_{MM}	±200	_	V
3	Charge device model (CDM)	V _{CDM}	±500	_	V
4	Latch-up current at T _A = 85°C	I _{LAT}	±100 ²	_	mA
4	Latch-up current at T _A = 85°C	I _{LAT}	±75 ³	_	mA

Parameter is achieved by design characterization on a small sample size from typical devices under typical conditions unless otherwise noted.

3.5 DC Characteristics

This section includes information about power supply requirements, I/O pin characteristics, and power supply current in various operating modes.

Table 7. DC Characteristics (Temperature Range = -40 to 85°C Ambient)

Num	С	Parameter	Symbol	Min	Typical	Max	Unit
1	Р	Supply voltage (run, wait and stop modes) 0 < f _{Bus} <10 MHz	V _{DD}	2.7	_	5.5	V
2	D	Minimum RAM retention supply voltage applied to V_{DD}	V _{RAM}	0.81		_	V
3	Р	Low-voltage Detection threshold $(V_{DD} \text{ falling})$	V_{LVD}		1.8		V
4	С	Power on RESET (POR) voltage	V _{POR}	0.9	1.4	1.7	V
5	Р	Input high voltage (V _{DD} > 5V) (all digital inputs)	V _{IH}	$0.70 \times V_{DD}$	_	_	V
6	Р	Input high voltage (2.7 V \leq V _{DD} \leq 5 V) (all digital inputs)	V _{IH}	$0.85 \times V_{DD}$	_	_	V
7	Р	Input low voltage (V _{DD} > 5 V) (all digital inputs)	V _{IL}	_	_	$0.30 \times V_{DD}$	V
8	Р	Input low voltage (2.7 V \leq V _{DD} \leq 5 V) (all digital inputs)	V _{IL}	_	_	$0.30 \times V_{DD}$	V
9	С	Input hysteresis (all digital inputs)	V _{hys}	$0.06 \times V_{DD}$	_	_	V
10	Р	Input leakage current (per pin) V _{In} = V _{DD} or V _{SS} , all input only pins	lin	_	0.025	1.0	μА
11	Р	High impedance (off-state) leakage current (per pin) $V_{In} = V_{DD}$ or V_{SS} , all input/output	loz	_	0.025	1.0	μΑ
12	С	Internal pullup/pulldown resistors ² (all port pins)	R _{PU}	20	45	65	kΩ
13	Р	Output high voltage (all ports) ^{3,4} $I_{OH} = -5 \text{ mA } (V_{DD} \ge 4.5 \text{ V})$ $I_{OH} = -3 \text{ mA } (V_{DD} \ge 3 \text{ V})$	V _{OH}	V _{DD} – 0.8	_	_	V
14	С	Maximum total I _{OH} for all port pins	[Іонт]	_	_	100	mA

² These pins meet JESD78A Class II (section 1.2) Level A (section 1.3) requirement of ± 100 mA.

³ This pin meets JESD78A Class II (section 1.2) Level B (section 1.3) characterization to ± 75 mA.

Table 7. DC Characteristics (Temperature Range = -40 to 85°C Ambient) (continued)

Num	С	Parameter	Symbol	Min	Typical	Max	Unit
15	Р	Output low voltage (port A) ⁴ $I_{OL} = 5 \text{ mA } (V_{DD} \ge 4.5 \text{ V})$ $I_{OL} = 3 \text{ mA } (V_{DD} \ge 3 \text{ V})$	V _{OL}		1	0.8 0.8	V
16	С	Maximum total lo∟ for all port pins	I _{OLT}	_	_	100	mA
17	С	dc injection current ^{5,6,7} $V_{ln} < V_{SS}, V_{ln} > V_{DD}$ Single pin limit Total MCU limit, includes sum of all stressed pins				0.2 0.8	mA mA
18	С	Input capacitance (all non-supply pins)	C _{In}	_	_	7	pF

This parameter is characterized and not tested on each device.

⁷ This parameter is characterized and not tested on each device.

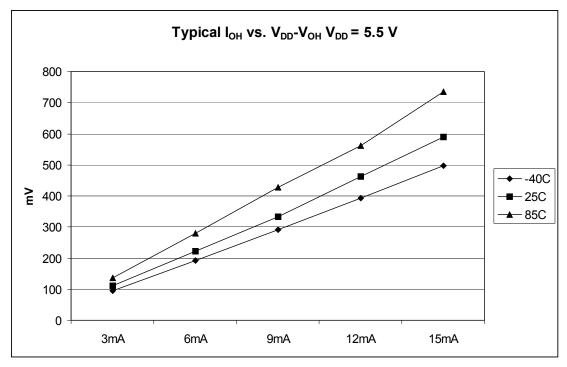


Figure 3. Typical I_{OH} vs. V_{DD} - V_{OH} (V_{DD} = 5.5 V)

 $^{^2}$ Measurement condition for pull resistors: $\rm V_{In}$ = $\rm V_{SS}$ for pullup and $\rm V_{In}$ = $\rm V_{DD}$ for pulldown.

 $^{^{3}}$ The I_{OH} is for high output drive strength.

⁴ It is tested under high output drive strength only.

All functional non-supply pins are internally clamped to V_{SS} and V_{DD} except the RESET/ V_{PP} which is internally clamped to V_{SS} only

⁶ Input must be current limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values for positive and negative clamp voltages, then use the larger of the two values.

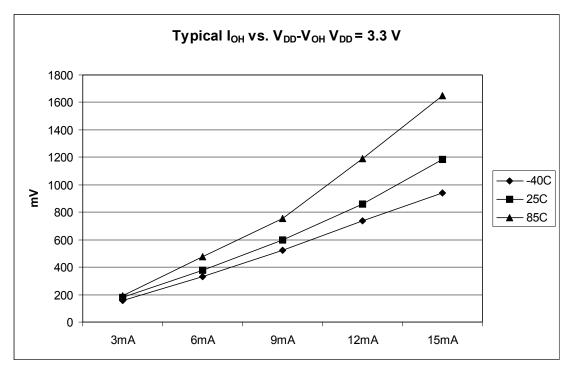


Figure 4. Typical I_{OH} vs. V_{DD} - V_{OH} (V_{DD} = 3.3 V)

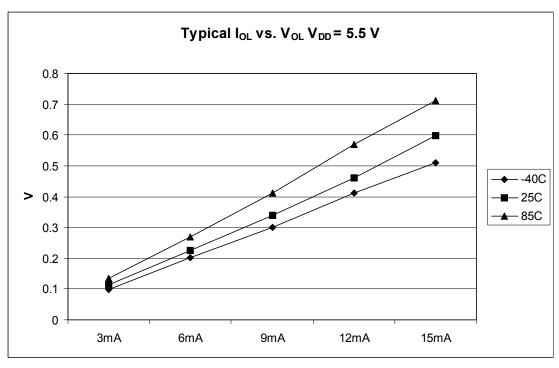


Figure 5. Typical I_{OL} vs. V_{OL} (V_{DD} = 5.5 V)

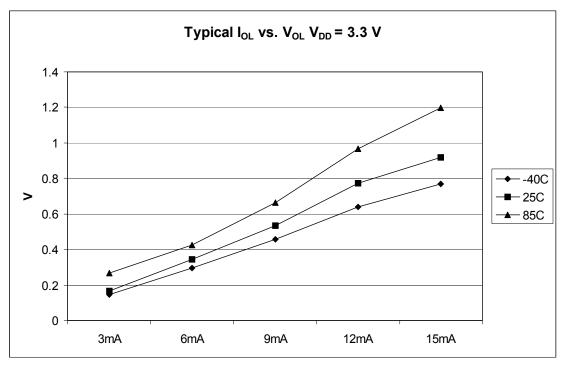


Figure 6. Typical I_{OL} vs. V_{OL} (V_{DD} = 3.3 V)

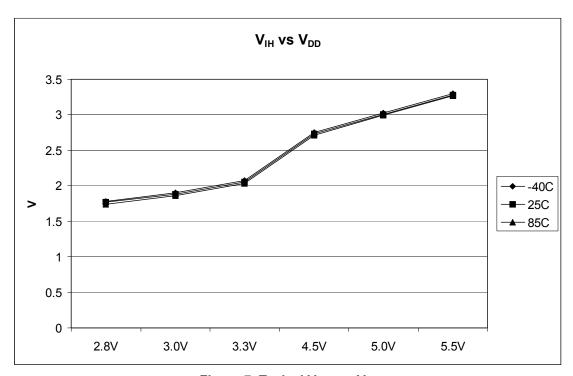


Figure 7. Typical V_{DD} vs. V_{IH}

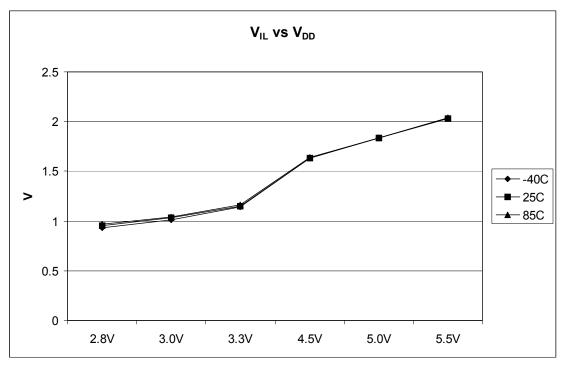


Figure 8. Typical $V_{\rm DD}$ vs. $V_{\rm IL}$

3.6 Supply Current Characteristics

Table 8. Supply Current Characteristics

Num	С	Parameter	Symbol	V _{DD} (V)	Typical ¹	Unit
				5	3.71	mA
	_	Run supply current ² measured at	D.	3.3	3.68	mA
1	Р	(f _{Bus} = 10 MHz)	RI _{DD10}	3	3.67	mA
				2.7	3.66	mA
				5	1.37	mA
	_	Wait mode supply current	\\/\/I	3.3	1.37	mA
2	2 P Wait mode supply current	wait mode supply current winds	WI _{DD1}	3	1.37	mA
					1.36	mA
			5	1.40	μА	
	_	Stop mode supply current SI _{DD}	Q1	3.3	1.35	μА
3	Р		OIDD	3	1.31	μА
				2.7	1.25	μА
				5	125.45	μА
		ADC adder from stop ³		3.3	122.04	μА
4	4 C	ADC adder from stop	_	3	121.59	μА
				2.7	121.22	μΑ
_		ACMP adder from stop		5	21	μΑ
5	С	(ACME = 1)	_	3	18.5	μА

15

Table 8. Supply Current Characteristics (continued)

Num	С	Parameter	Symbol	V _{DD} (V)	Typical ¹	Unit
6	_	RTI adder from stop	_	5	2.4	μА
0	C	with 1 kHz clock source enabled ⁴		3	1.9	μΑ
	_	LVI adder from stop		5	70	μА
8		(LVDE = 1 and LVDSE = 1)	_	3	65	μА

¹ Typicals are measured at 25 °C.

3.7 External (XOSC) and Internal (ICS) Oscillator Characteristics

Reference Figure 9 for crystal or resonator circuit.

² Does not include any dc loads on port pins

³ Required asynchronous ADC clock and LVD to be enabled.

⁴ Most customers are expected to find that auto-wakeup from stop can be used instead of the higher current wait mode. Wait mode typical is 1.37 mA at 5 V and 3 V with f_{Bus} = 10 MHz.

Table 9. External Oscillator Specifications (Temperature Range = -40 to 85°C Ambient)

Characteristic	Symbol	Min	Typical ¹	Max	Unit
Oscillator crystal or resonator (EREFS = 1) Low range, (IREFS = x) High range, FLL bypassed external (CLKS = 10, IREFS = x) High range, FLL engaged external (CLKS = 00, IREFS = 0)	f _{lo} f _{hi_byp} f _{hi_eng}	32 1 1	_ _ _	38.4 10 10	kHz MHz MHz
Load capacitors	C ₁ C ₂		See No	ote ²	
Feedback resistor Low range (32 kHz to 100 kHz) High range (1 MHz to 16 MHz)	R _F		10 1		MΩ MΩ
Series resistor Low range Low Gain (HGO = 0) High Gain (HGO = 1) High range Low Gain (HGO = 0) High Gain (HGO = 1) ≥ 8 MHz 4 MHz 1 MHz	R _S		0 100 0 0 10 20	_ _ _ _	kΩ
Crystal start-up time ^{3, 4} Low range High range	t CSTL tCSTH	_	500 4	_	ms
Square wave input clock frequency (EREFS = 0) FLL bypass external (CLKS = 10) FLL engaged external (CLKS = 00)	f _{extal}	0 0.03125		20 5	MHz
Average internal reference frequency - untrimmed	f _{int_ut}	25	31.25	41.66	kHz
Average internal reference frequency - trimmed	f _{int_t}	31.25	31.25	39.0625	kHz
DCO output frequency range - untrimmed	f _{dco_ut}	12.8	16	21.33	MHz
DCO output frequency range - trimmed	f _{dco_t}	16	16	20	MHz
Resolution of trimmed DCO output frequency at fixed voltage and temperature	Δf _{dco_res_t}	_	_	±0.2	%f _{dco}
Total deviation of trimmed DCO output frequency over voltage and temperature	Δf_{dco_t}	_	_	±2	%f _{dco}
FLL acquisition time ^{3,5}	t _{acquire}	_	_	1	ms
Long term Jitter ⁶ of DCO output clock (averaged over 2ms interval)	C _{Jitter}	_	_	0.6	%f _{dco}

¹ Data in Typical column was characterized at 3.0 V, 25 °C or is typical recommended value.

² See crystal or resonator manufacturer's recommendation.

 $^{^{\}rm 3}\,$ This parameter is characterized and not tested on each device.

⁴ Proper PC board layout procedures must be followed to achieve specifications.

⁵ This specification applies to any time the FLL reference source or reference divider is changed, trim value changed or changing from FLL disabled (FBELP, FBILP) to FLL enabled (FEI, FEE, FBE, FBI). If a crystal/resonator is being used as the reference, this specification assumes it is already running.

Jitter is the average deviation from the programmed frequency measured over the specified interval at maximum f_{BUS}. Measurements are made with the device powered by filtered supplies and clocked by a stable external clock signal. Noise injected into the FLL circuitry via V_{DD} and V_{SS} and variation in crystal oscillator frequency increase the C_{Jitter} percentage for a given interval.

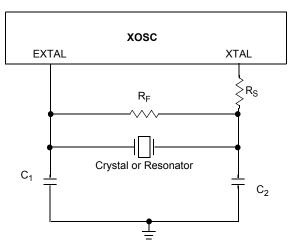


Figure 9. Typical Crystal or Resonator Circuit

3.8 AC Characteristics

This section describes ac timing characteristics for each peripheral system.

3.8.1 Control Timing

Table 10. Control Timing

Parameter	Symbol	Min	Typical	Max	Unit
Bus frequency (t _{cyc} = 1/f _{Bus})	f _{Bus}	0	_	10	MHz
Real time interrupt internal oscillator period	t _{RTI}	700	1000	1300	μS
External RESET pulse width ¹	t _{extrst}	150	_	_	ns
KBI pulse width ²	t _{KBIPW}	1.5 t _{cyc}	_	_	ns
KBI pulse width in stop ¹	t _{KBIPWS}	100	_	_	ns
Port rise and fall time (load = 50 pF) ³ Slew rate control disabled (PTxSE = 0) Slew rate control enabled (PTxSE = 1)	t _{Rise} , t _{Fall}	_	11 35	_	ns

¹ This is the shortest pulse that is guaranteed to pass through the pin input filter circuitry. Shorter pulses may or may not be recognized.

² This is the minimum pulse width that is guaranteed to pass through the pin synchronization circuitry. Shorter pulses may or may not be recognized. In stop mode, the synchronizer is bypassed so shorter pulses can be recognized in that case.

³ Timing is shown with respect to 20% V_{DD} and 80% V_{DD} levels. Temperature range –40°C to 85°C.

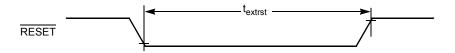


Figure 10. Reset Timing

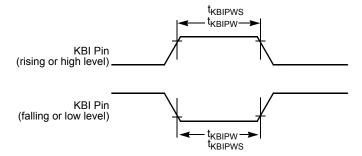


Figure 11. KBI Pulse Width

3.8.2 TPM/MTIM Module Timing

Synchronizer circuits determine the shortest input pulses that can be recognized or the fastest clock that can be used as the optional external source to the timer counter. These synchronizers operate from the current bus rate clock.

Table 11. TPM/MTIM Input Timing

Function	Symbol	Min	Max	Unit
External clock frequency	f _{TCLK}	0	f _{Bus} 1/4	MHz
External clock period	t _{TCLK}	4	_	t _{CYC}
External clock high time	t _{clkh}	1.5	_	t _{CYC}
External clock low time	t _{clkl}	1.5	_	t _{CYC}
Input capture pulse width	f _{ICPW}	1.5	_	t _{CYC}

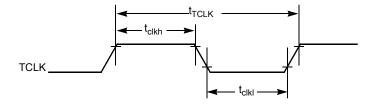


Figure 12. Timer External Clock

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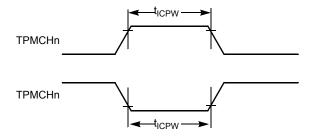


Figure 13. Timer Input Capture Pulse

3.9 Analog Comparator (ACMP) Electrical

Table 12. Analog Comparator Electrical Specifications

Characteristic	Symbol	Min	Typical	Max	Unit
Supply voltage	V_{DD}	2.7	_	5.5	V
Supply current (active)	I _{DDAC}	_	20	35	μΑ
Analog input voltage	V _{AIN}	V _{SS} - 0.3	_	V_{DD}	V
Analog input offset voltage ¹	V _{AIO}	_	20	40	mV
Analog Comparator hysteresis ¹	V_{H}	3.0	9.0	15.0	mV
Analog source impedance	R _{AS}	_	_	10	kΩ
Analog input leakage current	I _{ALKG}	_	_	1.0	μΑ
Analog Comparator initialization delay	t _{AINIT}	_	_	1.0	μS
Analog Comparator bandgap reference voltage	V_{BG}	1.208	1.208	1.208	V

¹ These data are characterized but not production tested. Measurements are made with the device entered STOP mode.

3.10 Internal Clock Source Characteristics

Table 13. Internal Clock Source Specifications

Characteristic	Symbol	Min	Typical ¹	Max	Unit
Average internal reference frequency — untrimmed	f _{int_ut}	25	31.25	41.66	kHz
Average internal reference frequency — trimmed	f _{int_t}	31.25	39.0625 ²	39.0625	kHz
DCO output frequency range — untrimmed	f _{dco_ut}	12.8	16	21.33	MHz
DCO output frequency range — trimmed	f _{dco_t}	16	20 ³	20	MHz
Resolution of trimmed DCO output frequency at fixed voltage and temperature	Δf _{dco_res_t}	_	_	0.2	%fdco
Total deviation of trimmed DCO output frequency over voltage and temperature	Δf_{dco_t}	_	_	2	%fdco
FLL acquisition time ^{4,5}	t _{acquire}	_	_	1	ms
Stop recovery time (FLL wakeup to previous acquired frequency) IREFSTEN = 0 IREFSTEN = 1	t _{wakeup}	_	100 86	_	μs

¹ Data in typical column was characterized at 3.0 V and 5.0 V, 25 °C or is typical recommended value.

² This value has been trimmed to 39.0625 kHz when out of factory

³ This value has been trimmed to 20 MHz when out of factory

3.11 ADC Characteristics

Table 14. 5 Volt 10-bit ADC Operating Conditions

Characteristic	Conditions	Symbol	Min	Typical ¹	Max	Unit
Supply voltage	Absolute	V_{DDAD}	2.7	_	5.5	V
Supply Voltage	Delta to V _{DD} (V _{DD} – V _{DDAD}) ²	ΔV_{DDAD}	-100	0	100	mV
Ground voltage	Delta to V _{SS} (V _{SS} – V _{SSAD}) ²	ΔV_{SSAD}	-100	0	100	mV
Ref voltage high	_	V _{REFH}	2.7	V_{DDAD}	V_{DDAD}	V
Ref voltage low	_	V _{REFL}	V _{SSAD}	V _{SSAD}	V _{SSAD}	V
Input voltage	_	V _{ADIN}	V _{REFL}	_	V _{REFH}	V
Input capacitance	_	C _{ADIN}	_	4.5	5.5	pF
Input resistance	_	R _{ADIN}	_	3	5	kΩ
Analog source resistance external to MCU	10-bit mode f _{ADCK} > 4MHz f _{ADCK} < 4MHz	R _{AS}	_	_	5 10	kΩ
	8-bit mode (all valid f _{ADCK})			_	10	
ADC conversion clock	High speed (ADLPC = 0)	f	0.4		8.0	MHz
frequency	Low power (ADLPC = 1)	f _{ADCK}	0.4	_	4.0	IVI⊓Z

¹ Typical values assume V_{DDAD} = 5.0 V, Temp = 25 °C, f_{ADCK} = 1.0 MHz unless otherwise stated. Typical values are for reference only and are not tested in production.

 $^{^{\}rm 4}~$ This parameter is characterized and not tested on each device.

⁵ This specification applies to any time the FLL reference source or reference divider is changed, trim value changed or changing from FLL disabled (FBILP) to FLL enabled (FEI, FBI).

² DC potential difference.

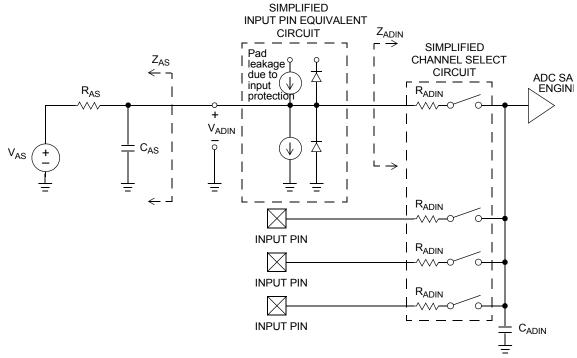


Figure 14. ADC Input Impedance Equivalency Diagram

Table 15. 10-bit ADC Characteristics ($V_{REFH} = V_{DDAD}, V_{REFL} = V_{SSAD}$)

Characteristic	Conditions	С	Symbol	Min	Typical ¹	Max	Unit
Supply current ADLPC=1 ADLSMP=1 ADCO=1		Т	I _{DDAD}	_	133	_	μΑ
Supply current ADLPC=1 ADLSMP=0 ADCO=1		Т	I _{DDAD}	_	218	_	μΑ
Supply current ADLPC=0 ADLSMP=1 ADCO=1		Т	I _{DDAD}	_	327		μΑ
Supply current ADLPC=0 ADLSMP=0 ADCO=1	V _{DDAD} ≤ 5.5 V	Р	I _{DDAD}	_	0.582	1	mA
Supply current	Stop, Reset, Module Off		I _{DDAD}		0.011	1	μА
ADC asynchronous clock	High Speed (ADLPC = 0)	Р	faració	2	3.3	5	MHz
source	Low Power (ADLPC = 1)	Р	f _{ADACK}	1.25	2	3.3	IVII IZ

Table 15. 10-bit ADC Characteristics ($V_{REFH} = V_{DDAD}$, $V_{REFL} = V_{SSAD}$) (continued)

Characteristic	Conditions	С	Symbol	Min	Typical ¹	Max	Unit		
Conversion time (Including	Short Sample (ADLSMP = 0)	Р	4	_	20	_	ADCK		
sample time)	Long Sample (ADLSMP = 1)		t _{ADC}	_	40	_	cycles		
Cample time	Short Sample (ADLSMP = 0)	Р	4	_	3.5	_	ADCK		
Sample time	Long Sample (ADLSMP = 1)	F	t _{ADS}	_	23.5	_	cycles		
Total upadiusted arror	10-bit mode	Р	Г	_	±1	±2.5	LSB ²		
Total unadjusted error	8-bit mode	P	E _{TUE}	_	±0.5	±1.0	LOD		
	10-bit mode	Р	DNL	_	±0.5	±1.0	LSB ²		
Differential non-linearity	8-bit mode	Р	P DINL	_	±0.3	±0.5	LOD		
	Monotonicity and no-missing-code guaranteed								
Integral non-linearity	10-bit mode	0	C INL	_	±0.5	±1.0	LSB ²		
integral non-linearity	8-bit mode		IINL	_	±0.3	±0.5	LOD		
Zero-scale error	10-bit mode	Р	F	_	±0.5	±1.5	LSB ²		
Zero-scale error	8-bit mode	F	E _{ZS}	_	±0.5	±0.5	LOD		
Full-scale error	10-bit mode	Р	Г	_	±0.5	±1.5	LSB ²		
$V_{ADIN} = V_{DDA}$	8-bit mode	P	E _{FS}	_	±0.5	±0.5	LOD		
Quantization arror	10-bit mode	_	Е	_	_	±0.5	LSB ²		
Quantization error	8-bit mode	D	E _Q	_	_	±0.5	LOD		
Input leakage error	10-bit mode	D	Е	_	±0.2	±2.5	- LSB ²		
pad leakage ³ * Ras	8-bit mode	ט	E _{IL}	_	±0.1	±1	LOD		

Typical values assume V_{DDAD} = 5.0 V, Temp = 25 °C, f_{ADCK} = 1.0 MHz unless otherwise stated. Typical values are for reference only and are not tested in production.

3.12 AC Characteristics

This section describes AC timing characteristics for each peripheral system.

3.12.1 Control Timing

Table 16. Control Timing

Characteristic	Symbol	Min	Typical	Max	Unit
Bus frequency $(t_{cyc} = 1/f_{Bus})$	f _{Bus}	DC	_	10	MHz
Real time interrupt internal oscillator period	t _{RTI}	700	1000	1300	μS

MC9RS08LA8 Series MCU Data Sheet, Rev. 2

² 1 LSB = $(V_{REFH} - V_{REFL})/2^N$

³ Based on input pad leakage current. Refer to pad electrical.

Table 16	Control	Timina	(continued)
I abic it		HILLING	(COIILIIIGEA)

Characteristic	Symbol	Min	Typical	Max	Unit
External RESET pulse width ¹	t _{extrst}	150		_	ns
KBI pulse width ²	t _{KBIPW}	1.5 tcyc		_	ns
KBI pulse width in stop ¹	t _{KBIPWS}	100		_	ns
Port rise and fall time (load = 50 pF) ³ Slew rate control disabled (PTxSE = 0) Slew rate control enabled (PTxSE = 1)	t _{Rise} , t _{Fall}		11 35	_	ns

¹ This is the shortest pulse that is guaranteed to pass through the pin input filter circuitry. Shorter pulses may or may not be recognized.

 $^{^3}$ Timing is shown with respect to 20% V_{DD} and 80% V_{DD} levels. Temperature range –40 °C to 85 °C.

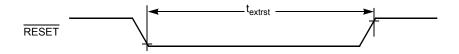


Figure 15. Reset Timing

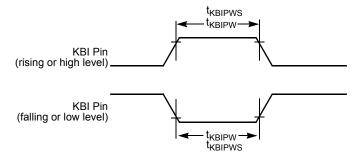


Figure 16. KBI Pulse Width

3.13 Flash Specifications

This section provides details about program/erase times and program-erase endurance for the flash memory. For detailed information about program/erase operations, see the reference manual.

Table 17. Flash Characteristics

Characteristic	Symbol	Min	Typical ¹	Max	Unit
Supply voltage for program/erase	V_{DD}	2.7	_	5.5	V
Program/Erase voltage	V_{PP}	11.8	12	12.2	V
V _{PP} current Program Mass erase	I _{VPP_prog}	1	1 1	200 100	μ Α μ Α
Supply voltage for read operation 0 < f _{Bus} < 10 MHz	V_{Read}	2.7	_	5.5	V

MC9RS08LA8 Series MCU Data Sheet, Rev. 2

² This is the minimum pulse width that is guaranteed to pass through the pin synchronization circuitry. Shorter pulses may or may not be recognized. In stop mode, the synchronizer is bypassed so shorter pulses can be recognized in that case.

Table 17. Flash Characteristics (continued)

Characteristic	Symbol	Min	Typical ¹	Max	Unit
Byte program time	t _{prog}	20	_	40	μS
Mass erase time	t _{me}	500	_	_	ms
Cumulative program HV time ²	t _{hv}	_	_	8	ms
Total cumulative HV time (total of t _{me} & t _{hv} applied to device)	t _{hv_total}	_	_	2	hours
HVEN to program setup time	t _{pgs}	10	_	_	μS
PGM/MASS to HVEN setup time	t _{nvs}	5	_	_	μS
HVEN hold time for PGM	t _{nvh}	5	_	_	μS
HVEN hold time for MASS	t _{nvh1}	100	_	_	μS
V _{PP} to PGM/MASS setup time	t _{vps}	20	_	_	ns
HVEN to VPP hold time	t _{vph}	20	_	_	ns
V _{PP} rise time ³	t _{vrs}	200	_	_	ns
Recovery time	t _{rcv}	1	_	_	μS
Program/erase endurance T _L to T _H = -40 °C to 85 °C	_	1000	_	_	cycles
Data retention	t _{D_ret}	15	_		years

Typicals are measured at 25 °C.

³ Fast V_{PP} rise time may potentially trigger the ESD protection structure, which may result in over current flowing into the pad and cause permanent damage to the pad. External filtering for the V_{PP} power source is recommended. An example V_{PP} filter is shown in Figure 17.

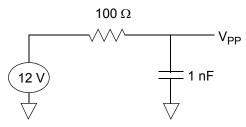
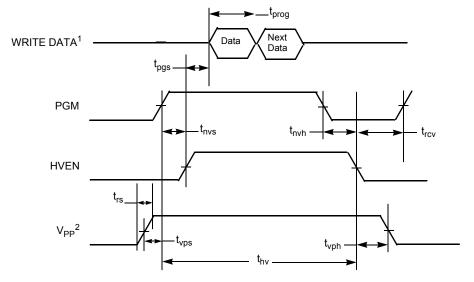


Figure 17. Example V_{PP} Filtering

 $^{^2}$ t_{hv} is the cumulative high voltage programming time to the same row before next erase. Same address can not be programmed more than twice before next erase.



- Next Data applies if programming multiple bytes in a single row, refer to MC9RS08LA8 Series Reference Manual
- ² V_{DD} must be at a valid operating voltage before voltage is applied or removed from the V_{PP} pin.

MASS

HVEN t_{nvs} t_{nvh1} t_{rs} t_{vph}

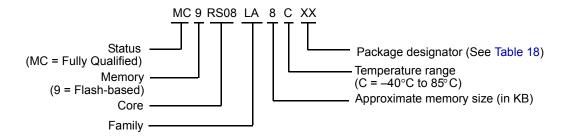
Figure 18. Flash Program Timing

 $^{1}~\rm V_{DD}$ must be at a valid operating voltage before voltage is applied or removed from the $\rm V_{PP}$ pin.

Figure 19. Flash Mass Erase Timing

4 Ordering Information

This section contains ordering information for MC9RS08LA8 devices. See below for an example of the device numbering system.



5 Package Information and Mechanical Drawings

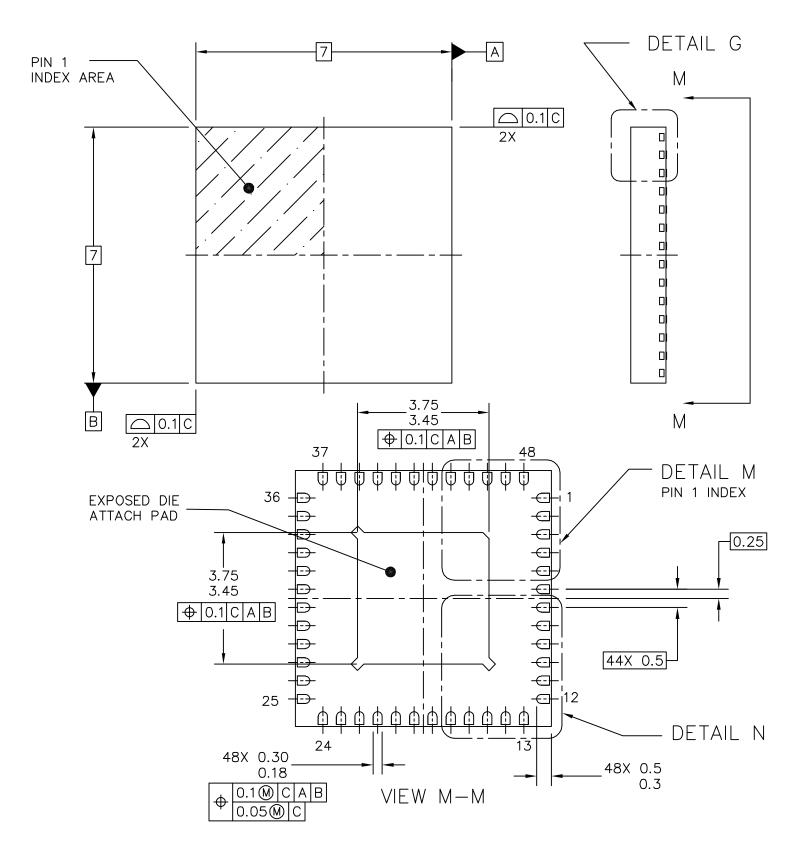
Table 18 provides the available package types and their document numbers. The latest package outline/mechanical drawings are available on the MC9RS08LA8 Series Product Summary pages at http://www.freescale.com.

To view the latest drawing, either:

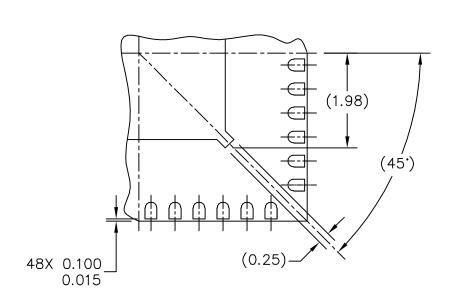
- Click on the appropriate link in Table 18, or
- Open a browser to the Freescale® website (http://www.freescale.com), and enter the appropriate document number (from Table 18) in the "Enter Keyword" search box at the top of the page.

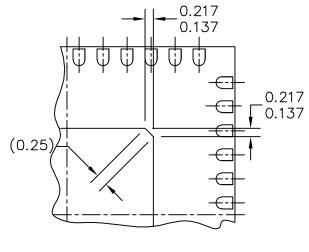
Device Number	Men	nory		Package	
Device Humber	FLASH	RAM	Type	Designator	Document No.
MC9RS08LA8	8 KB	256 bytes	48-Pin QFN	FT	98ARL10606D
WICSKSUOLAO	O NB	200 bytes	48-Pin LQFP	LF	98ASH00962A

Table 18. Device Numbering System



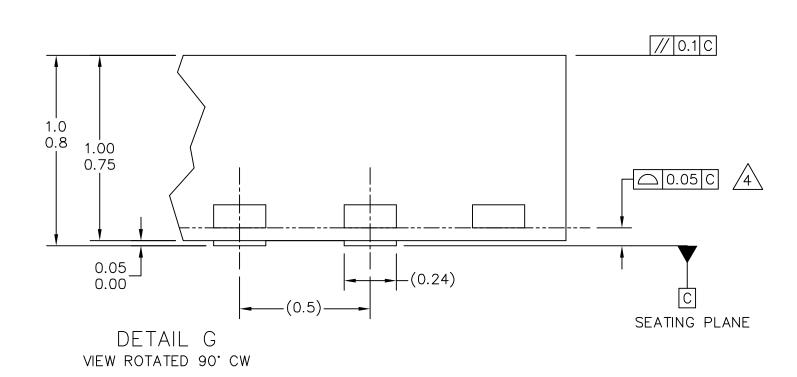
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TITLE: THERMALLY ENHANCED QUA	AD	DOCUMENT NO	: 98ARL10606D	REV: 0
FLAT NON-LEADED PACKAGE	` '	CASE NUMBER	: 1975–01	29 AUG 2007
48 TERMINAL, 0.5 PITCH (7 X	/ X 1) [STANDARD: JE	DEC-MO-220 VKKD-2	2





DETAIL N
PREFERRED CORNER CONFIGURATION

DETAIL M
PREFERED PIN 1 BACKSIDE IDENTIFIER



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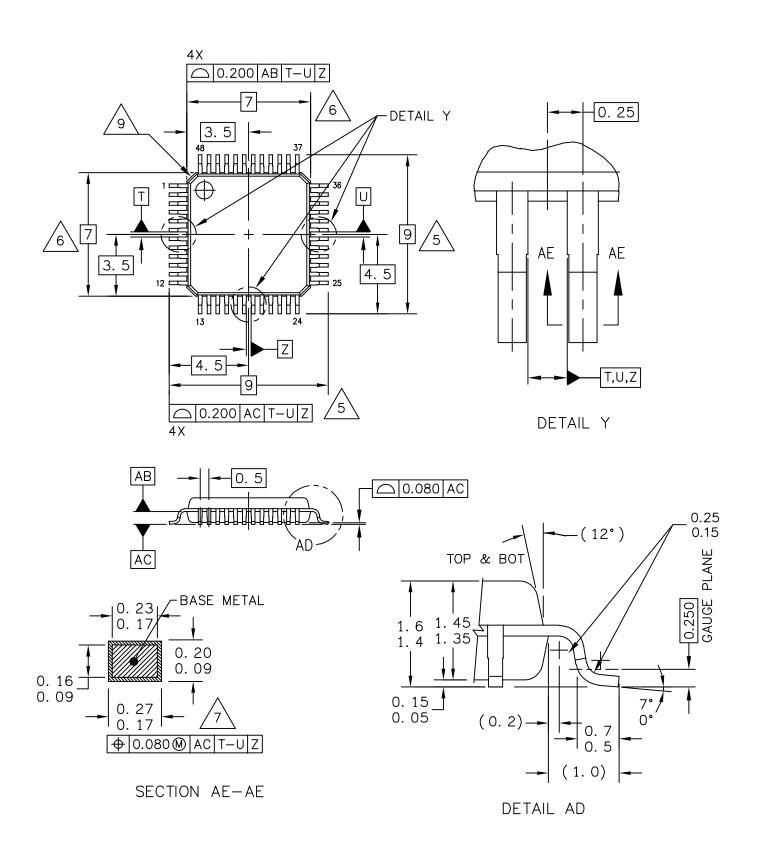
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4. Coplanarity applies to leads, corner leads, and die attach pad.

5. MIN METAL GAP SHOULD BE 0.2MM.

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- 3. DATUM PLANE AB IS LOCATED AT BOTTOM OF LEAD AND IS COINCIDENT WITH THE LEAD WHERE THE LEAD EXITS THE PLASTIC BODY AT THE BOTTOM OF THE PARTING LINE.
- 4. DATUMS T, U, AND Z TO BE DETERMINED AT DATUM PLANE AB.



DIMENSIONS TO BE DETERMINED AT SEATING PLANE AC.



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THIS DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. DAMBAR PROTRUSION SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED 0.350.

8. MINIMUM SOLDER PLATE THICKNESS SHALL BE 0.0076.



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